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(71) Applicants (for all designated States except US): UNIVERSITAET KARLSRUHE [DE/DE]; Institut for Experimental Kernphysik, Postfach 6980, 76128 Karlsruhe (DE). AKADEMIA GORNICZO-HUTNICZA [PL/PL]; Al. Mickiewicza, 30, PL-30-059 Krakow (PL). UNIVERSITÉ LOUIS PASTEUR [FR/FR]; Laboratoire d'Electronique et de Physique des, Systèmes Instrumentaux, BP 28-23, Rue du Loess, 67037 Strasbourg (FR).

CENTRE NATIONAL DE LA RECHERCHE SCIENTIFIQUE [FR/FR]; 3 rue Michel Ange, F-75794 Paris Cedex 16 (FR). INSTITUTE OF ELECTRON TECHNOLOGY [PL/PL]; Al. Lotnikow, 32/46, PL-02-668 Warszawa (PL). FONDAZIONE PER ADROTERAPIA ONCOLOGICA - TERA [IT/IT]; Via Puccini, 11, I-28100 Novara (IT). UNIVERSITE DE GENEVE [CH/CH]; Départment de Radiologie, 24, rue Micheli-du-Crest, CH-1211 Geneve 14 (CH). INSTYTUT FIZYKI JADROWEJ IM. H. NIEWODNICZANSKIEGO [PL/PL]; Ul. Radzikowskiego, 152, PL-31-342 Krakow (PL).
(71) Applicants and
(72) Inventors: CACCIA, Massimo [IT/IT]; c/o Università degli Studi dell'Insubria, Dipartimento di Scienze CC.FF.MM., Via Valleggio, 11, I-22100 Como (IT). CONTE, Leopoldo [IT/IT]; c/o Università degli Studi dell'Insubria, Dipartimento di Scienze Cliniche e Biologiche, Padiglione Antonini, Via Ottorino Rossi, 9, 21100 VARESE (IT).
[Continued on next page]
(54) Title: MONOLITHIC ACTIVE PIXEL DOSIMETER

(57) Abstract: A monolithic active pixel dosimeter, provided with at least a sensing cell (202), having at least a junction sensing element (218). The junction sensing element (218) includes a sensing region (227), having a first type of conductivity, and a charge collecting region (228), contiguous to the sensing region (227) and having a second type of conductivity. The sensing cell (202) further includes an ohmic region (230) at least partially overlapping and extending laterally outside the charge collecting region (228), and an annular insulating region (231), abutting the ohmic region (230), so as to form an insulating junction (232) surrounding both the ohmic region and the charge collection region (228).
(72) Inventors; and
(75) Inventors/Applicants (for US only): ALEMI, Mario [IT/IT]; c/o Università degli Studi dell'Insubria, Dipartimento di Scienze CC.FF.MM., Via Valleggio, 11, I-22100 Como (IT). CAPPELLINI, Chiara [IT/IT]; c/o Università degli Studi dell'Insubria, Dipartimento di Scienze CC.FF.MM., Via Valleggio, 11, I-22100 Como (IT). AIROLDI, Antonello, Luigi [IT/IT]; Via Gabriele d'Annunzio, 2, I-23887 Olgiate Molgora (IT). BIANCHI, Carla [IT/IT]; Università degli Studi dell'Insubria, Dipartimento di Scienze Cliniche et Biologiche, Padiglione Antonini, Via Ottorino Rossi, 9, I-21100 Varese (IT). NOVARIO, Raffaele [IT/IT]; c/o Università degli Studi dell'Insubria, Dipartimento di Scienze Cliniche e Biologiche, Padiglione Antonini, Via Ottorino Rossi, 9, I-21100 Varese (IT). DE BOER, Wim [DE/DE]; c/o Universitaet Karlsruhe, Institut for Experimental Kernphysik, Postfach 6980, 76128 Karlsruhe (DE). GRIGORIEV, Eugene [CH/DE]; c/o Universitaet Karlsruhe, Institut for Experimental Kernphysik, Postfach 6980, 76128 Karlsruhe (DE). NIEMIEC, Halina [PL/PL]; c/o Akademia Gor-niczo-Hutnicza, Al. Mickiewicza, 30, PL-30-059 Krakow (PL). KUCEWICZ, Wojciech [PL/PL]; c/o Akademia Gorniczo-Hutnicza, A1. Mickiewicza 30, PL-30-059 Krakow (PL). CANNILLO, Francesco [IT/FR]; c/o Universite Louis Pasteur, Laboratoire d'Electronique et de Physique des, Systèmes Instrumentaux, BP 28 23, rue du Loess, F-67037 Strasbourg (FR). CLAUSS, Gilles [FR/FR]; c/o Université Louis Pasteur, Laboratoire d'Electronique et de Physique des, Systèmes Instrumentaux, 23, rue du Loess - BP 28, F-67037 Strasbourg (FR). COLLEDANI, Claude [FR/FR]; c/o Université Louis Pasteur, Laboratoire d'Electronique et de Physique des, Systèmes Instrumentaux, 23, rue du Loess - BP 28, F-67037 Strasbourg (FR). DEPTUCH, Grzegorz [PL/FR]; c/o Université Louis Pasteur, Laboratoire d'Electronique et de Physique des, Systèmes Instrumentaux, 23, rue du Loess - BP 28, F-67037 Strasbourg (FR). DULINSKI, Wojciech [PL/FR]; c/o Université Louis Pasteur, Laboratoire d'Electronique et de Physique des, Systèmes Instrumentaux, 23, rue du Loess - BP 28, F-67037 Strasbourg (FR). GRABIEC, Piotr [PL/PL]; c/o Institute of Electron Technology, Al. Lotnikow, 32/46, PL-02-668 Warszawa (PL). MARCZEWSKI, Jacek [PL/PL]; c/o Institute of Electron Technology, Al. Lotnikow 32/46, PL-02-668 Warszawa (PL). DOMANSKI, Krysztof [PL/PL]; c/o Institute of Electron Technology, Al. Lotnikow 32/46, PL-02-668 Warszawa (PL). JAROSZEWICZ, Bohdan [PL/PL]; c/o Institute of Electron Technology, Al. Lotnikow 32/46, PL-02-668 Warszawa (PL). KUCHARSKI, Krzysztof [PL/PL]; c/o

Institute of Electron Technology, A1. Lotnikow 32/46, PL-02-668 Warszawa (PL). BADANO, Laura [IT/IT]; c/o TERA - Sezione di Milano, c/o Università di Milano Bicocca, Dipartimento di Scienze dei Materiali, Via Cozzi, 53, I-20125 Milano (IT). FERRANDO, Ornella [IT/IT]; c/o TERA - Sezione di Milano, c/o Università di Milano Bicocca, Dipartimento di Scienze dei Materiali, Via Cozzi, 53, I-20125 Milano (IT). POPOWSKI, Georg $[\mathrm{BE} / \mathrm{CH}]$; c/o Université de Genève, Départment de Radiologie, Rue Micheli-du-Crest, 24, CH-1211 Geneve 14 (CH). ZALEWSKA, Agnieszka [PL/PL]; c/o Instytut Fizyki Jadrowej Im. H., Niewodniczanskiego, Ul. Radzikowskiego 152, PL-31-342 Krakow (PL). CZERMAK, Adam [PL/PL]; c/o Instytut Fizyki Jadrowej Im. H., Niewodniczanskiego, Ul. Radzikowskiego 152, PL-31-342 Krakow (PL).
(74) Agents: JORIO, Paolo et al.; c/o Studio Torta S.r.l., Via Viotti, 9, I-10121 Torino (IT).
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